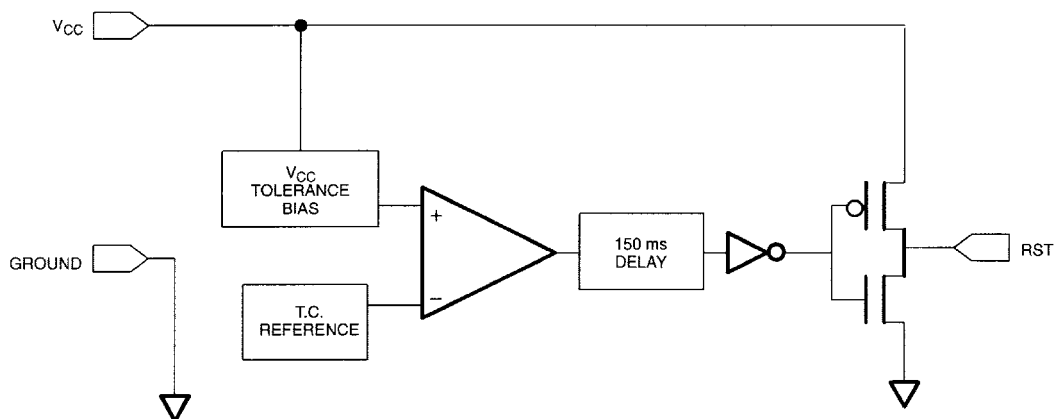


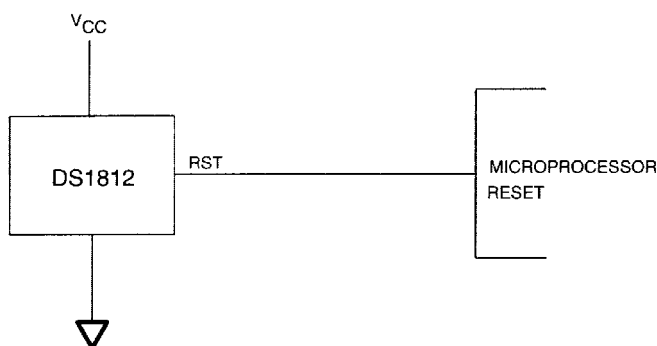
OPERATION - POWER MONITOR

The DS1812 provides the function of detecting out-of-tolerance power supply conditions and warning a processor-based system of impending power failure. When V_{CC} is detected as out-of-tolerance, the RST signal is asserted. On power-up, RST is kept active for approximately 150 ms after the power supply has reached the selected tolerance. This allows the power supply and microprocessor to stabilize before RST is released.

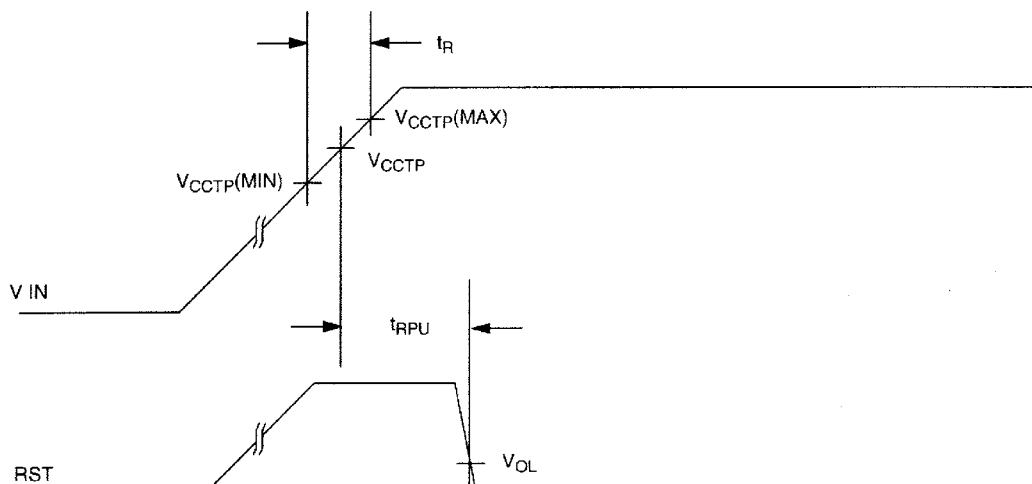
BLOCK DIAGRAM (CMOS OUTPUT) Figure 1



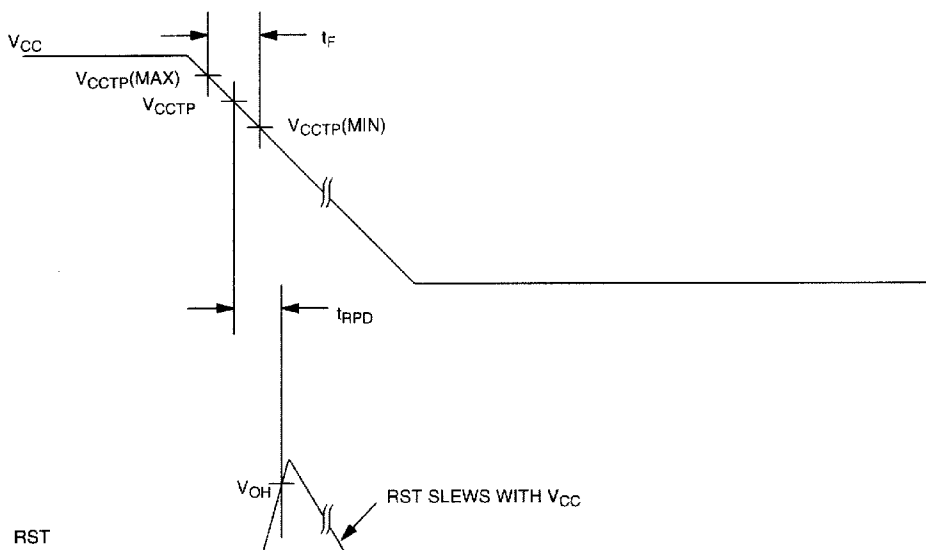
APPLICATION EXAMPLE Figure 2



TIMING DIAGRAM: POWER-UP Figure 3



TIMING DIAGRAM: POWER-DOWN Figure 4



ABSOLUTE MAXIMUM RATINGS*

Voltage on V_{CC} Pin Relative to Ground	-0.5V to +7.0V
Voltage on RST Relative to Ground	-0.5V to $V_{CC} + 0.5V$
Operating Temperature	-40°C to +85°C
Storage Temperature	-55°C to +125°C
Soldering Temperature	260°C for 10 seconds

* This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

RECOMMENDED DC OPERATING CONDITIONS (-40°C to +85°C)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	V_{CC}	0.0		5.5	V	1

DC ELECTRICAL CHARACTERISTICS (-40°C to +85°C; $V_{CC}=1.2V$ to 5.5V)

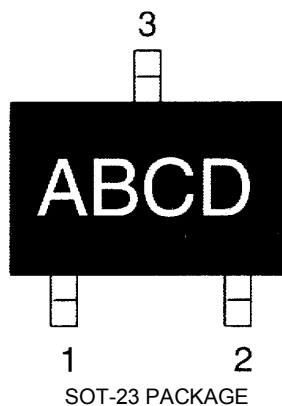
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Output Voltage @ 0-500 μA	V_{OH}	V_{CC} -0.5V	V_{CC} -0.1V		V	1
Output Current @ 2.4 volts	I_{OH}		350		μA	2
Output Current @ 0.4 volts	I_{OL}	+10			mA	2
Operating Current $V_{CC} < 5.5$	I_{CC}		30	40	μA	3
V_{CC} Trip Point (DS1812-5)	V_{CCTP}	4.50	4.62	4.75	V	1
V_{CC} Trip Point (DS1812-10)	V_{CCTP}	4.25	4.35	4.49	V	1
V_{CC} Trip Point (DS1812-15)	V_{CCTP}	4.00	4.13	4.24	V	1
Output Capacitance	C_{OUT}			10	pF	

AC ELECTRICAL CHARACTERISTICS (-40°C to +85°C; $V_{CC}=1.2V$ to 5.5V)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
RESET Active Time	t_{RST}	100	150	300	ms	
V_{CC} Detect to RST	t_{RPD}		2	5	μs	
V_{CC} Slew Rate (V_{CCTP} (MAX) to V_{CCTP} (MIN))	t_F	300			μs	
V_{CC} Slew Rate (V_{CCTP} (MIN) to V_{CCTP} (MAX))	t_R	0			ns	
V_{CC} Detect to RST	t_{RPU}	100	150	300	ms	4

NOTES:

1. All voltages are referenced to ground.
2. Measured with $V_{CC} \geq 2.7$ volts.
3. Measured with RST output open.
4. $t_R = 5 \mu s$.

PART MARKING CODES

“A”, “B”, & “C” represent the device type.

810	-	DS1810
811	-	DS1811
812	-	DS1812
813	-	DS1813
815	-	DS1815
816	-	DS1816
817	-	DS1817
818	-	DS1818

“D” represents the device tolerance.

A	-	5%
B	-	10%
C	-	15%
D	-	20%